

IGBT MODULE (Single-in-Line)

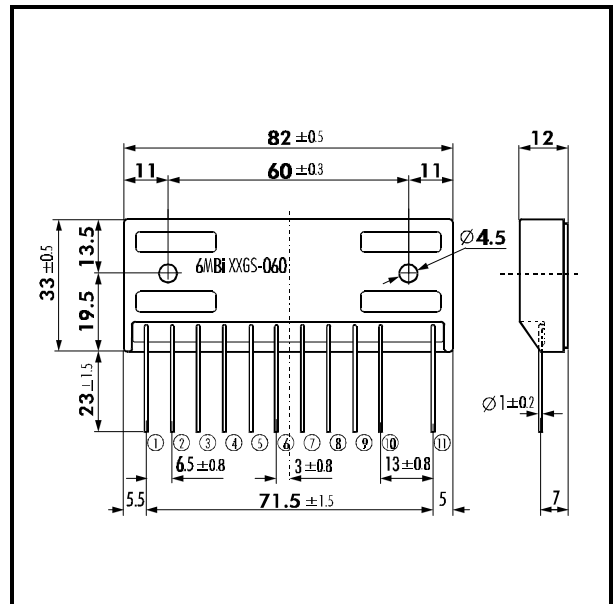
■ Features

- Square RBSOA
- Low Saturation Voltage
- Improved FWD Characteristic
- Minimized Internal Stray Inductance

■ Applications

- High Power Switching
- A.C. Motor Controls
- D.C. Motor Controls

■ Outline Drawing



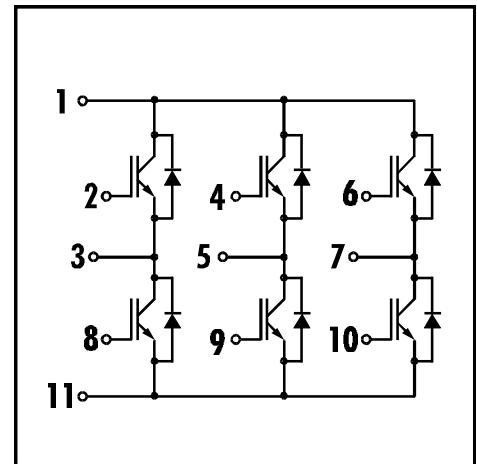
■ Maximum Ratings and Characteristics

• Absolute Maximum Ratings (T_c=25°C)

Items	Symbols	Ratings	Units
Collector-Emitter Voltage	V _{CEs}	600	V
Gate -Emitter Voltage	V _{GES}	± 20	V
Collector Current	Continuous	I _C	20
	1ms	I _{C PULSE}	40
	Continuous	-I _C	20
	1ms	-I _{C PULSE}	40
Max. Power Dissipation	P _C	70	W
Operating Temperature	T _i	+150	°C
Storage Temperature	T _{stg}	-40 ~ +125	°C
Isolation Voltage	V _{is}	2000	V
Screw Torque	Mounting *1	1.7	Nm

Note: *1:Recommendable Value; 1.3 ~ 1.7 Nm (M4)

■ Equivalent Circuit



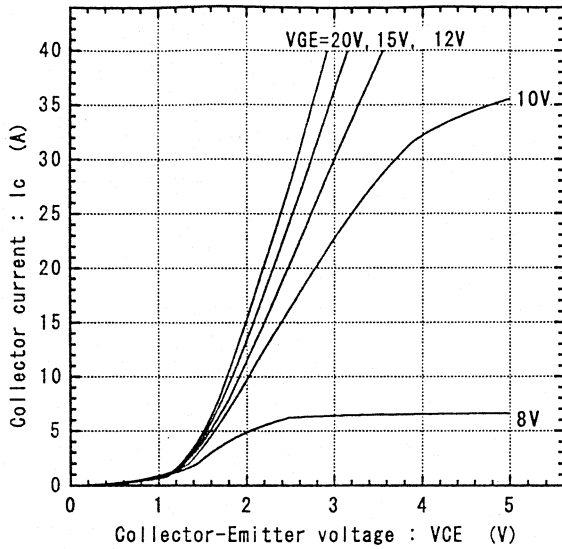
• Electrical Characteristics (at T_j=25°C)

Items	Symbols	Test Conditions	Min.	Typ.	Max.	Units
Zero Gate Voltage Collector Current	I _{CEs}	V _{GE} =0V V _{CE} =600V			1.0	mA
Gate-Emitter Leakage Current	I _{GES}	V _{CE} =0V V _{GE} =± 20V			100	nA
Gate-Emitter Threshold Voltage	V _{GE(th)}	V _{GE} =20V I _C =10mA	5.5		8.5	V
Collector-Emitter Saturation Voltage	V _{CE(sat)}	V _{GE} =15V I _C =10A			2.8	V
Input capacitance	C _{ies}	V _{GE} =0V		1300		pF
Output capacitance	C _{oes}	V _{CE} =10V		300		
Reverse Transfer capacitance	C _{res}	f=1MHz		72		
Turn-on Time	t _{ON}	V _{CC} =300V			1.2	μs
	t _r	I _C =20A			1.0	
Turn-off Time	t _{OFF}	V _{GE} =± 15V			1.0	
	t _f	R _G =120Ω			0.35	
Diode Forward On-Voltage	V _F	I _F =20A V _{GE} =0V			3.0	V
Reverse Recovery Time	t _{rr}	I _F =20A			300	ns

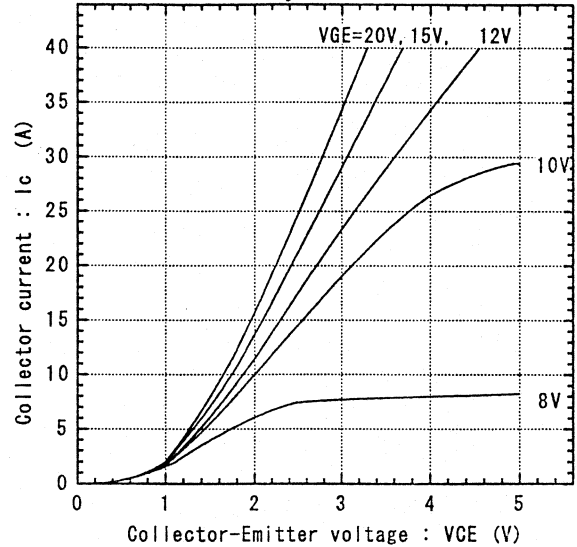
• Thermal Characteristics

Items	Symbols	Test Conditions	Min.	Typ.	Max.	Units
Thermal Resistance	R _{th(f-c)}	IGBT			1.79	°C/W
	R _{th(f-c)}	Diode			2.50	
	R _{th(c-f)}	With Thermal Compound		0.06		

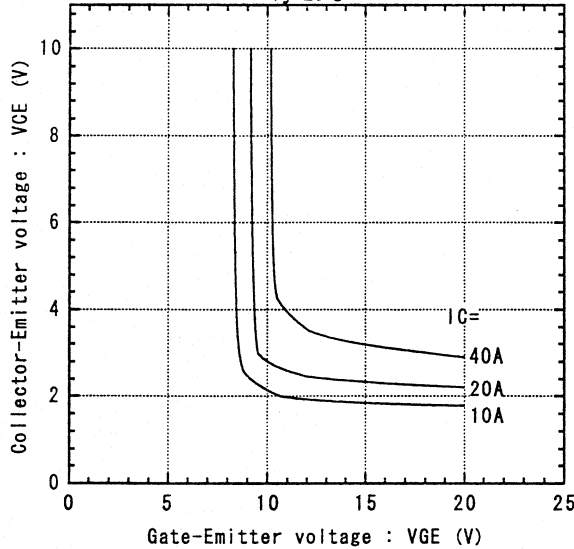
Collector-Emitter voltage vs. Collector current
T_j=25°C



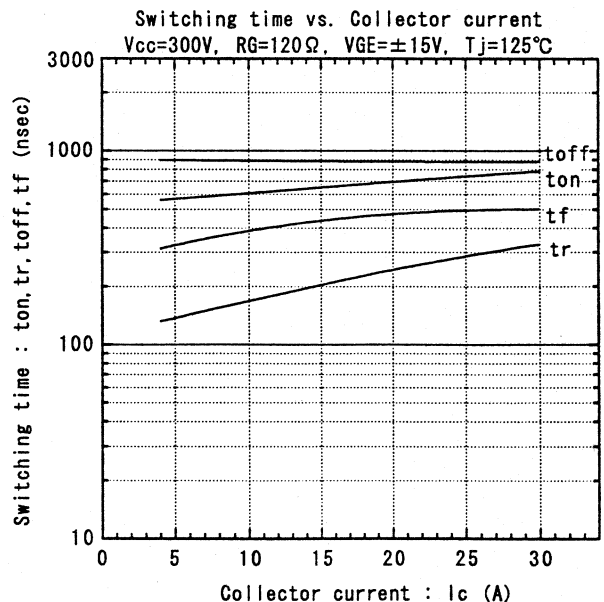
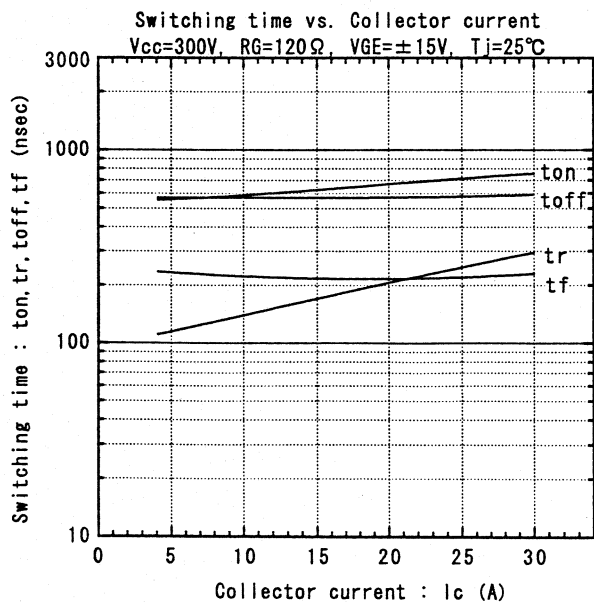
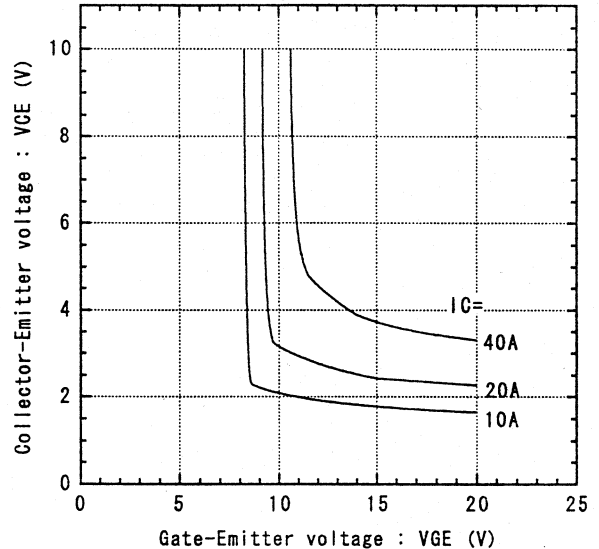
Collector-Emitter voltage vs. Collector current
T_j=125°C

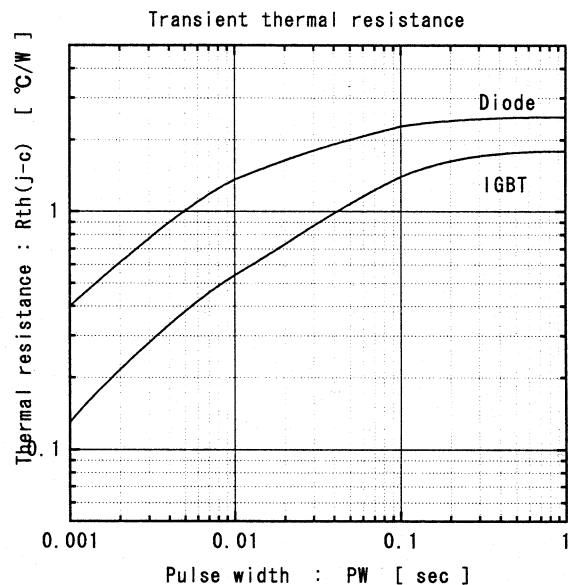
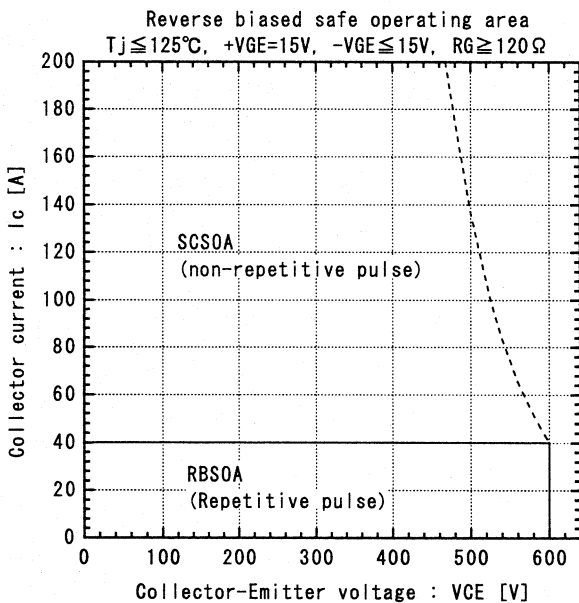
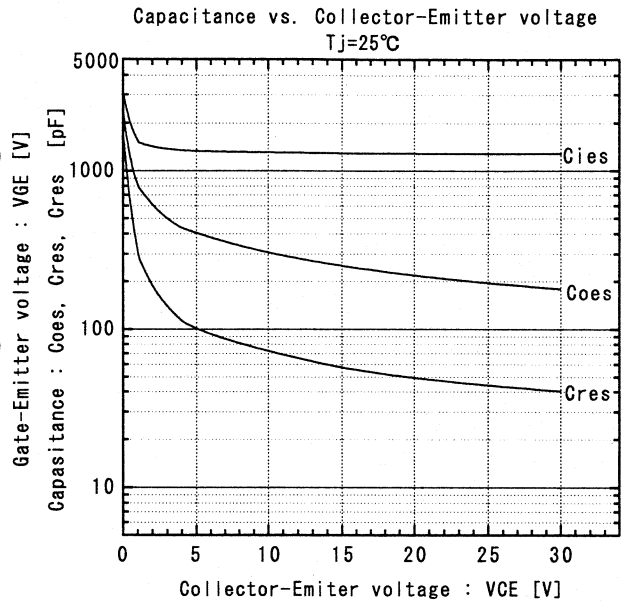
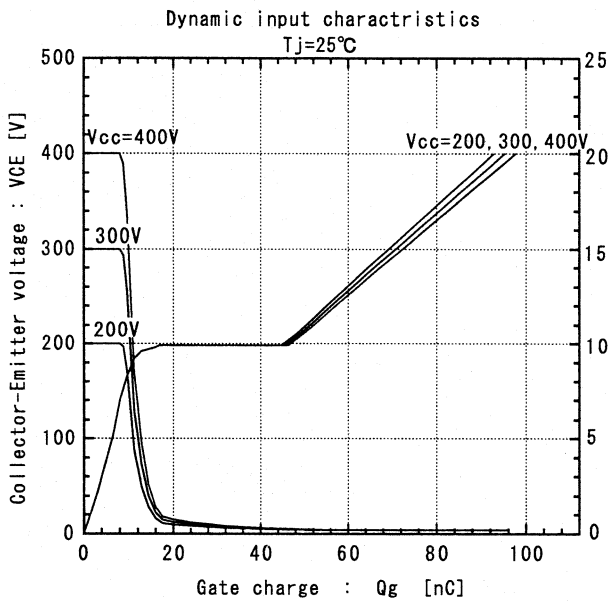
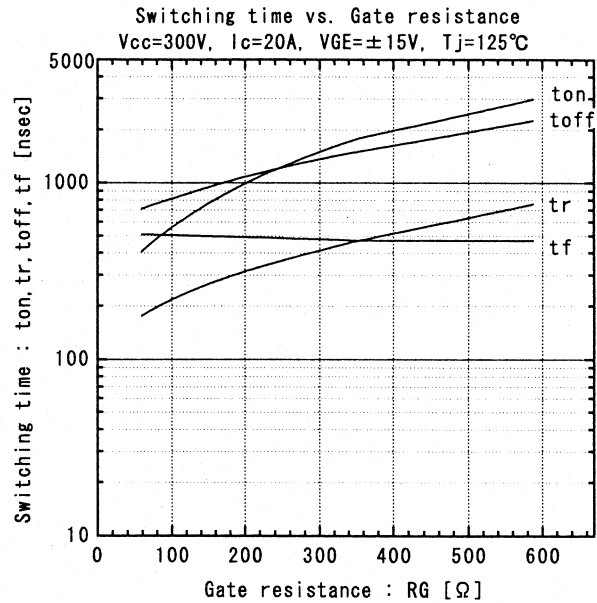
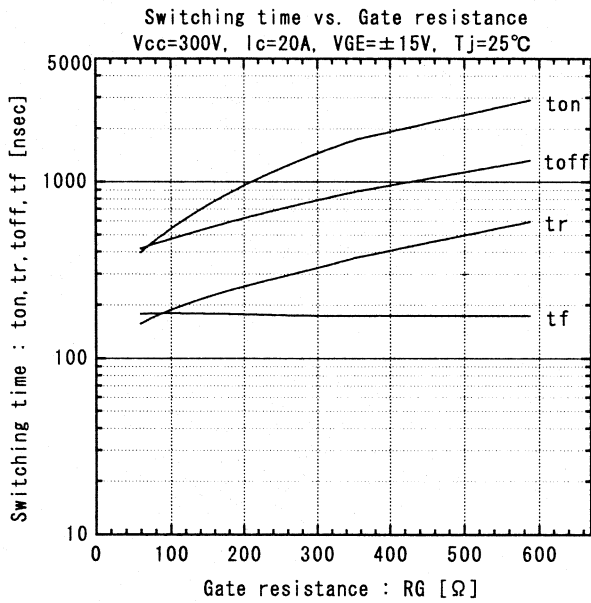


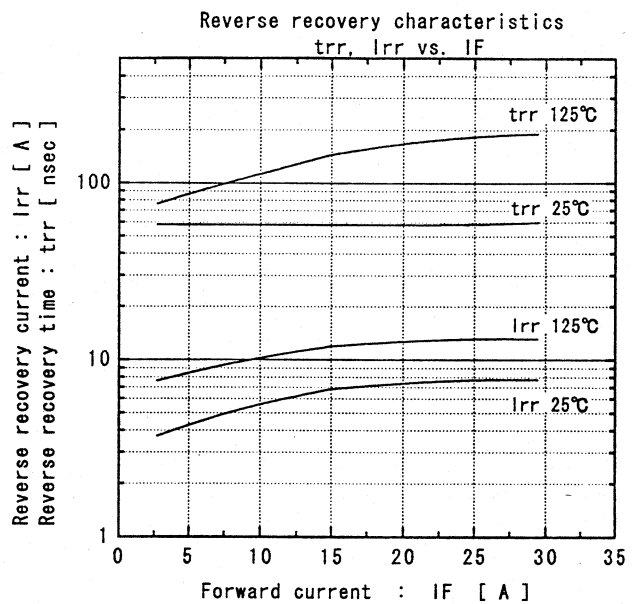
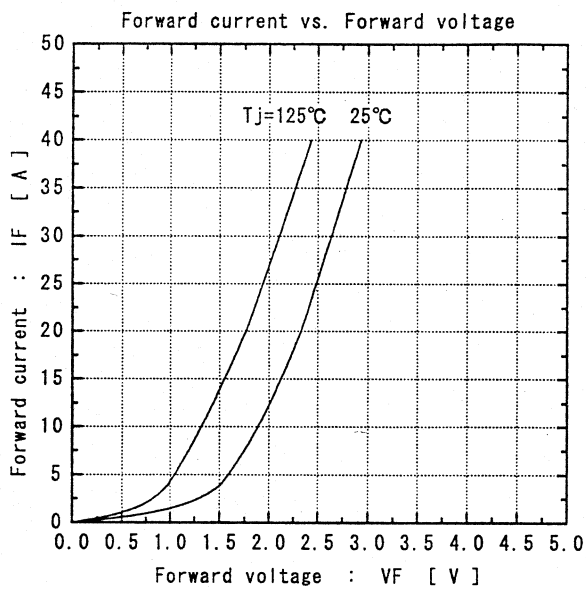
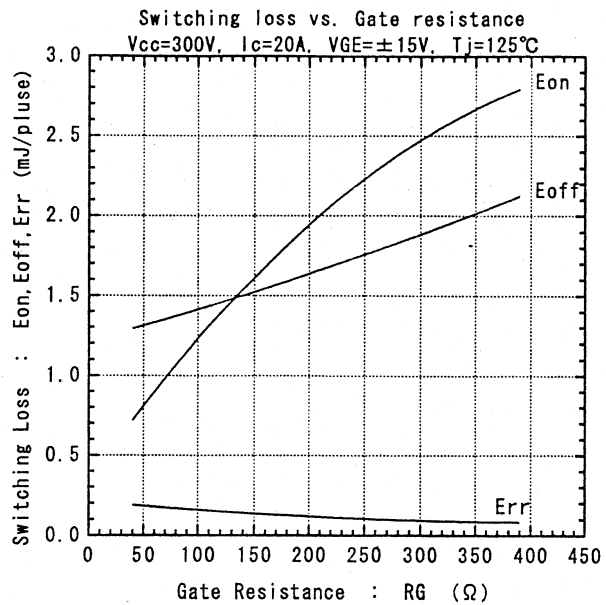
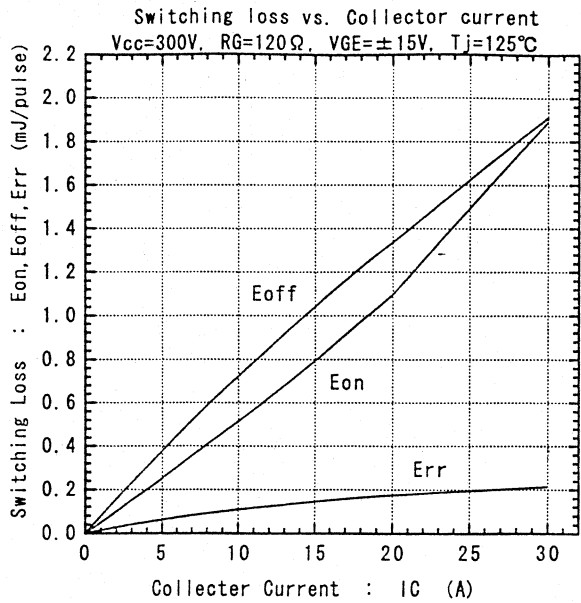
Collector-Emitter vs. Gate-Emitter voltage
T_j=25°C



Collector-Emitter vs. Gate-Emitter voltage
T_j=125°C







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